
	<h2 style="color: red;">FQD7N20LTM</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQD7N20LTM</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 200V 5.5A DPAK</p> <p><b>Datenblätter:</b> <a href="#">1.FQD7N20LTM.pdf</a> <a href="#">2.FQD7N20LTM.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 3970 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQD7N20LTM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 200V 5.5A DPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	3970 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	2.5W (Ta), 45W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.5A (Tc)
Rds On (Max) @ Id, Vgs	750 mOhm @ 2.75A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

FQD7N20LTM ist neu im Original, Suche FQD7N20LTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD7N20LTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD7N20LTM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQD7N20TF</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 5.3A DPAK</p>	 <p><b>FQD7N20TF</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 5.3A DPAK</p>	 <p><b>FQD7N20LTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 5.5A DPAK</p>	 <p><b>FQD7N20LTF</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 5.5A DPAK</p>
 <p><b>FQD7N20TM_F080</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 5.3A DPAK</p>	 <p><b>FQD7N20TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 5.3A DPAK</p>	 <p><b>FQD7N20</b> F FQD7N20 F</p>	 <p><b>FQD7N20LTF</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 5.5A DPAK</p>

### heiße Teile

Mehr

<a href="#">FQD6N40CTM</a>	<a href="#">FQD6N40CTM</a>	<a href="#">FQD6N50CTF</a>	<a href="#">FQD6N50CTF</a>	<a href="#">FQD6N50CTM</a>
<a href="#">FQD6N50CTM</a>	<a href="#">FQD6N60C</a>	<a href="#">FQD6N60CS</a>	<a href="#">FQD6N60CTF</a>	<a href="#">FQD6N60CTM</a>
<a href="#">FQD6N60CTM</a>	<a href="#">FQD6P25TM</a>	<a href="#">FQD6P25TM</a>	<a href="#">FQD7N10L</a>	<a href="#">FQD7N10LTF</a>
<a href="#">FQD7N10LTF</a>	<a href="#">FQD7N10LTM</a>	<a href="#">FQD7N10LTM</a>	<a href="#">FQD7N10TF</a>	<a href="#">FQD7N10TM</a>
<a href="#">FQD7N10TM</a>	<a href="#">FQD7N20L</a>	<a href="#">FQD7N20LTF</a>	<a href="#">FQD7N20LTF</a>	<a href="#">FQD7N20LTM</a>
<a href="#">FQD7N20TF</a>	<a href="#">FQD7N20TF</a>	<a href="#">FQD7N20TM</a>	<a href="#">FQD7N20TM</a>	<a href="#">FQD7N30TM</a>
<a href="#">FQD7N30TM</a>	<a href="#">FQD7P06TF</a>	<a href="#">FQD7P06TF</a>	<a href="#">FQD7P06TM</a>	<a href="#">FQD7P06TM</a>
<a href="#">FQD7P06TM_F080</a>	<a href="#">FQD7P06TM_F080</a>	<a href="#">FQD7P06TM_NB82050</a>	<a href="#">FQD7P06TM_NB82050</a>	<a href="#">FQD7P10TF</a>
<a href="#">FQD7P20TF</a>	<a href="#">FQD7P20TF</a>	<a href="#">FQD7P20TM</a>	<a href="#">FQD7P20TM</a>	<a href="#">FQD7P20TM_F080</a>
<a href="#">FQD7P20TM_F080</a>	<a href="#">FQD8P10TF</a>	<a href="#">FQD8P10TF</a>	<a href="#">FQD8P10TF_NB82052</a>	<a href="#">FQD8P10TF_NB82052</a>

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